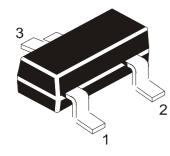
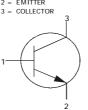


NPN SILICON PLANAR EPITAXIAL TRANSISTORS



PIN CONFIGURATION (NPN) 1 = BASE

1 = BASE 2 = EMITTER 3 = COLLECTOR



CMBT8098 CMBT8099

SOT-23 Formed SMD Package

Marking CMBT8098- KA CMBT8099- KB

ABSOLUTE MAXIMUM RATING

DESCRIPTION	SYMBOL	CMBT8098	CMBT8099	UNITS
Collector Base Voltage	V _{CBO}	60	80	V
Collector Emitter Voltage	V _{CEO}	60	80	V
Emitter Base Voltage	V _{EBO}	6	V	
Collector Current Continuous	Ι _C	5	mA	
Power Dissipation T _a =25 ^o C (Note1)	P _D	2	mW	
Derate Above 25°C		1	mW/⁰C	
Power Dissipation T _a =25 ^o C (Note2)	PD	3	mW	
Derate Above 25°C			mW/⁰C	
Operating And Storage Junction Temperature Range	T _j ,T _{stg}	- 55 1	°C	

Thermal Resistance

Junction to Ambient (Note1)	R _{th(j-a)}	556	°C/W
Junction to Ambient (Note2)	R _{th(j-a)}	417	°C/W

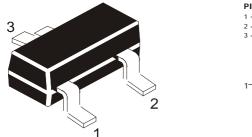
Note (1) FR-5 Board=25.4 x 19.05 x 1.58 mm (1.0 x 0.75 x 0.062 inches.)

Note (2) Alumina Substrate=10.16 x 7.62 x 0.61 mm (0.4 x 0.3 x 0.024 inches.) 99.5% alumina.

ELECTRICAL CHARACTERISTICS (T_a=25° C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Base Voltage	V _{CBO}	I _C =100μA, I _E =0				
		CMBT8098	60			V
		СМВТ8099	80			V
Collector Emitter Voltage	V _{CEO}	I _C =10mA, I _B =0				
		CMBT8098	60			V
		CMBT8099	80			V
Emitter Base Voltage	V _{EBO}	I _E =10μΑ, I _C =0	6.0			V
Collector Cut Off Current	CES	V _{CE} =60V, I _B =0			0.1	μA
Collector Cut Off Current	Сво	CMBT8098				
		V_{CB} =60V, I _E =0			0.1	μΑ
		CMBT8099				
		V _{CB} =80V, I _E =0			0.1	μA
Emitter Cut Off Current	Ево	$V_{EB}=6V, I_{C}=0$			0.1	μA

NPN SILICON PLANAR EPITAXIAL TRANSISTORS



PIN CONFIGURATION (NPN) 1 = BASE 2 = EMITTER 3 = COLLECTOR 1

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ELECTRICAL CHARACTERISTICS (T_a=25° C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
DC Current Gain	h _{FE} *	I _C =1mA, V _{CE} =5V	100		300	
		I _C =10mA, V _{CE} =5V	100			
		I _C =100mA, V _{CE} =5V	75			
Collector Emitter Saturation Voltage	V _{CE(sat)} *	I _C =100mA, I _B =5mA			0.4	V
		I _C =100mA, I _B =10mA			0.3	V
Base Emitter On Voltage	V _{BE(on)} *	CMBT8098				
		I _C =1mA,V _{CE} =5V	0.5		0.7	V
		СМВТ8099				
		I _C =10mA,V _{CE} =5V	0.6		0.8	V

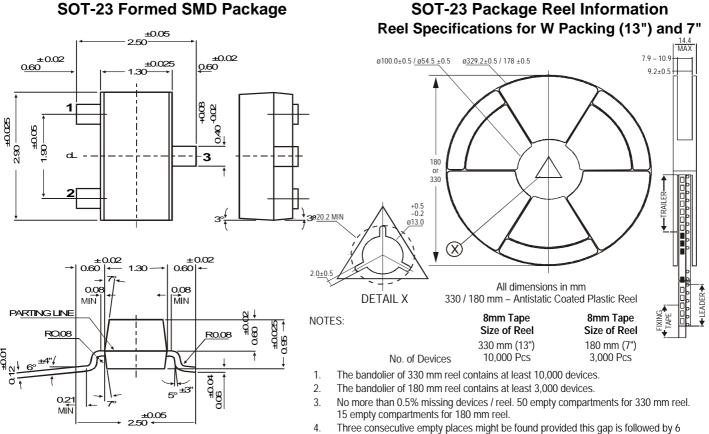
Small Signal Characteristics

Current Gain Bandwidth Product	f _T	I _C =10mA, V _{CE} =5V,f=100MHz	150		MHz
Output Capacitance	C _{obo}	I _E =0, V _{CB} =5V, f=1MHz		6.0	pF
Input Capacitance	C _{ibo}	I _C =0, V _{EB} =0.5V, f=1MHz		25	pF

*Pulse Test: Pulse Width < 300ms, Duty Cycle<2%

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SOT-23 Formed SMD Package

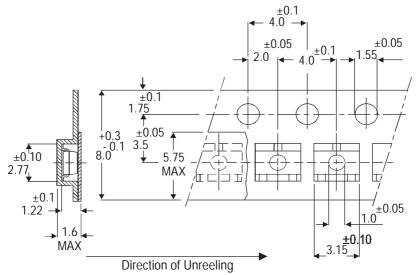


Three consecutive empty places might be found provided this gap is followed by 6 4 consecutive devices.

All dimensions in mm

The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end 5 of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Tape Specification for SOT-23 Surface Mount Device



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12 K	17" x 15" x 13.5"	192 K	12 kgs
			9" x 9" x 9"	51 K	19" x 19" x 19"	408 K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10 K	17" x 15" x 13.5"	300 K	16 kgs

CMBT8098 CMBT8099

SOT-23 Formed SMD Package

Disclaimer

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